

<b>FORM 1449*</b> <b>INFORMATION DISCLOSURE STATEMENT</b>  <b>IN AN APPLICATION</b>  (Use several sheets if necessary)	Docket Number: 10873.0884USD1	Application Number: filed here within
	Applicant: Yorito OTA	
	Filing Date: filed here within	Group Art Unit: n/a

U.S. PATENT DOCUMENTS							
EXAMINER INITIAL	DOCUMENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE	
Sun	US 6,221,685	April 2001	ICHINOSE et al.				
	US 5,557,118	Sept. 1996	HASHIMOTO				
	US 6,154,475	Nov. 2000	SOREF et al.				
	US 5,270,554	Dec. 1993	Palmour				
	US 4,762,806	Aug. 1988	Suzuki et al.				
	US 5,905,277	May 1999	Ota et al.				
FOREIGN PATENT DOCUMENTS							
	DOCUMENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
						YES	NO
Sun	JP 6-97107	April 1994	Japan				
	JP 5-102497	April 1993	JAPAN				
	JP 5-175239	July 1993	JAPAN			Abstract	
	JP 2000-101099	April 2000	JAPAN			Abstract	
	JP 60-142568	July 1985	JAPAN			Abstract	
	JP 10-321646	Dec. 1998	JAPAN			Abstract	
Sun	JP 5-90572	April 1993	JAPAN			Abstract	
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)							
Sun		"Nickel and Molybdenum Ohmic Contacts on Silicon Carbide", Institute of Physics Conference Series No. 142, pp 577-580, 1996.					

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EXAMINER	<i>S. [signature]</i>	DATE CONSIDERED	3/18/05
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form for next communication to the Applicant.			